

# ESD7382MUT5G

Data Sheet

Micro-Packaged Diodes for ESD Protection

Manufacturers	ON Semiconductor, LLC	
Package/Case	X3DFN-2	
Product Type	Integrated Circuits (ICs)	
RoHS		
Lifecycle		Images are for reference only
Please submit RFQ for ESD7382MUT5G or <u>Email to us: sales@ovaga.com</u> We will contact you in 12 hours.		

## **General Description**

The ESD7382 is designed to protect voltage sensitive components that require ultra-low capacitance from ESD events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection ondesigns where board space is at a premium. Because of its lowcapacitance, it is suited for use in high frequency designs such as USB 2.0 high speed and antenna line applications.

### Features

Ultra-Low Capacitance: 0.37 pF

Low Clamping Voltage

Small Body Outline Dimensions:  $0.60\ \text{mm}\,x\,0.30\ \text{mm}$ 

Low Body Height: 0.3 mm

Stand-off Voltage: 5.0 V

Low Leakage

Insertion Loss: 0.030 dBm

Response Time is < 1 ns

Low Dynamic Resistance < 1

IEC61000-4-2 Level 4 ESD Protection

These Devices are Pb-Free, Halogen Free/BFR Free and are RoHSCompliant

#### **Related Products**



ON Semiconductor, LLC X2DFN-2

**ESDM3051N2T5G** 



ON Semiconductor, LLC UDFN-14

ESD8708MUTAG



ON Semiconductor, LLC

SZESD8551MXWT5G

X2DFNW2

#### SZESD7241MXWT5G



ON Semiconductor, LLC X2DFNW2



SZESD7424MUT5G ON Semiconductor, LLC

#### ESD7321MUT5G

UDFN-2



ON Semiconductor, LLC X3DFN-2

#### ESD8111PFCT5G



ON Semiconductor, LLC DFN-2

#### ESD5581N2T5G



ON Semiconductor, LLC X2DFN-2

# Application

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